# Comparison between trion and exciton electronic properties in CdSe and PbS nanoplatelets 

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#### Abstract

The optoelectronic properties of metal chalcogenide colloidal nanoplatelets are often interpreted in terms of excitonic states. However, recent spectroscopic experiments evidence the presence of trion states, enabled by the slow Auger recombination in these structures. We analyze how the presence of an additional charge in trions modifies the emission energy and oscillator strength as compared to neutral excitons. These properties are very sensitive to dielectric confinement and electronic correlations, which we describe accurately using image-charge and variational Quantum Monte Carlo methods in effective mass Hamiltonians. We observe that the giant oscillator strength of neutral excitons is largely suppressed in trions. Both negative and positive trions are redshifted with respect to the exciton, and their emission energy increases with increasing dielectric mismatch between the platelet and its surroundings, which is a consequence of the self-energy potential. Our results are consistent with experiments in the literature, and assess on the validity of previous theoretical approximations.


## Introduction

The outstanding optical features of semiconductor colloidal nanoplatelets (NPLs) makes them a broad target of study and application in devices. $\underline{\underline{\underline{1}} \underline{\underline{4}}}$ As compared to colloidal quantum dots, the quasi-2D nature of NPLs conveys several distinct properties of interest, including precisely controllable thickness - which enables narrow emission linewidths--, large absorption cross-sections and bright luminescence resulting from the giant oscillator strength effect. ${ }^{\underline{2}-\underline{\underline{4}}}$ Several efforts have been carried out in synthesis methods to control the morphology, dimensions and composition, as well as in characterization of the subsequent optoelectronic properties. ${ }^{4-7}$ In parallel, theoretical models have been developed to understand the underlying electronic structure. In most cases, such models focus on neutral excitons, $\underline{\underline{8}-\underline{22}}$ which is typically the dominant emitting species in colloidal nanocrystals.

There is however increasing evidence that the emission spectrum of core-only and core/shell

CdSe NPLs at low temperatures has a significant contribution from charged excitons (tri-ons)..$\underline{23-29}$ The formation of radiative trions is enabled by the higher dimensionality of NPLs as compared to nanocrystals, which slows down Auger relaxation processes. $\mathbf{3 0}-33$ Trions are of high technological interest for optoelectronic applications. The spin-zero configuration in one of the bands suppresses the electron-hole exchange interaction, and hence the optically dark ground state observed in the fine structure of neutral excitons, which is convenient for efficient luminescence. ${ }^{25}$ They also enable two-color emission through shake-up processes ${ }^{34}$ -which are particularly strong in colloidal NPLs ${ }^{26,35}$, provide a photoresponsive system for chemical sensing through surface adsorption ${ }^{23}$ and form a natural two-level quantum system for quantum information applications. 28

Understanding how the electronic structure of trions differs from that of excitons is a prerequesite for rational design of applications. In a recent work, Peng et al. analyzed the emission spectra of exciton and trion states in CdSe NPLs with 4.5 monolayers core thickness surrounded by thin $\mathrm{CdS} / \mathrm{ZnS}$ shells. $\underline{\text { 28 }}$ By comparing time-resolved photoluminescence data with tight-binding simulations, which accounted for electronic correlations using a configuration interaction (CI) approach, they assigned the observed spectral peaks to neutral excitons and negative trions. The latter showed binding energies of about 10.5 meV , and similar oscillator strength to that of the exciton band edge transition. In parallel, Ayari et al. investigated the negative trion emission spectra in CdSe core-only NPLs with the same thickness, but varying lateral dimensions. $\underline{\underline{29}}$ They observed stronger trion binding energies, widely modulated by the lateral confinement ( $18-36 \mathrm{meV}$ ). By comparing time-integrated photoluminescence data with rate equation models and effective mass-CI calculations of the electronic structure, they inferred that the oscillator strength of trions is one order of magnitude weaker than that of the excitons. The seemingly contradicting conclusions in the two studies call for independent assessment.

To better understand how the photophyics of trions in NPLs differs from that of excitons, one must account for the fact that electronic correlations are particularly challenging
to model in these structures. Unlike quantum dots, NPLs lie in a Coulomb dominated, intermediate confinement regime, $\underline{\underline{13}, \underline{14}}$ where the strong electron-hole attraction -arising from dielectric confinement and the quasi-2D geometry- leads to small excitonic radii. ${ }^{36}$ Such a short-range interaction makes CI calculations based on envelope wave functions miss correlation energy. $\underline{\underline{37} \text {. } 38 \text { By contrast, the electron-electron (or hole-hole) repulsions in trions, which }}$ are also enhanced by the quasi-2D geometry and the dielectric confinement, are longerranged interactions and hence better captured by CI models. Conclusions about the balance between attractive and repulsive forces in these systems must be revisited using methods which account for both of them on equal footing.

In this work, we calculate the electronic structure of excitons and trions in colloidal NPLs using effective mass Hamiltonians which include electronic correlations though a variational Quantum Monte Carlo (VQMC) description. This method has been recently shown to outperform CI approaches in these systems. $\underline{39}$ We choose CdSe and PbS NPLs, which are systems of current interest for direct applications including solar cells,, , 41 photodetectors operating in the near infrared, $\underline{\underline{42}}$ light-emitting diodes $\underline{43-45}$ and lasers. $\underline{46}$ We provide an overview on the differences between neutral excitons and trions, and examine some of the approximations used in earlier models, such as the description of dielectric confinement with Rytova-Keldysh (RK) potential and neglecting self-energy corrections. ${ }^{29}$ We shall see that of both positive and negative trions are bound for typical NPL dimensions, with binding energies which (for CdSe) exceed room temperature thermal energy. The repulsions in trions lead to a moderate increase of the excitonic Bohr radius and induce a significant suppression of the oscillator strength as compared to neutral excitons. Similar to excitons, dielectric confinement leads to an overall increase of the trion emission energy.

## Methods

We calculate exciton and trion ground state energies and wave functions closely following Ref. 39. Briefly, we solve effective mass Hamiltonians of the form:
$H=\sum_{i=1}^{N_{e}} \hat{h}_{e}+\sum_{i=1}^{N_{h}} \hat{h}_{h}+\sum_{i=1}^{N_{e}} \sum_{j=1}^{N_{h}} V_{c}\left(\mathbf{r}_{i}, \mathbf{r}_{j}\right)+1 / 2 \sum_{i=1}^{N_{e}} \sum_{j \neq i}^{N_{e}} V_{c}\left(\mathbf{r}_{i}, \mathbf{r}_{j}\right)+1 / 2 \sum_{i=1}^{N_{h}} \sum_{j \neq i}^{N_{h}} V_{c}\left(\mathbf{r}_{i}, \mathbf{r}_{j}\right)+E_{\text {gap }}$.
where $N_{e}$ and $N_{h}$ is the number of electrons and holes, while $\hat{h}_{e}$ and $\hat{h}_{h}$ are the corresponding single-particle Hamiltonians:

$$
\begin{equation*}
\hat{h}_{i}=\left(\frac{\hat{\mathbf{p}}_{\perp}^{2}}{2 m_{\perp, i}}+\frac{\hat{p}_{z}^{2}}{2 m_{z, i}}+V\right) . \tag{2}
\end{equation*}
$$

Here, $m_{\perp}$ and $\hat{\mathbf{p}}_{\perp}\left(m_{z, i}\right.$ and $\left.\hat{p}_{z}^{2}\right)$ are the in-plane (out-of-plane) effective mass and momentum operators, respectively. $V=V^{\text {conf }}+\Sigma$, is the single particle potential, with $V^{\text {conf }}$ the spatial confinament potential -zero inside the cuboidal NPL, infinite outside it-, and $\Sigma$ the selfenergy potential arising from dielectric confinement. $V_{c}\left(\mathbf{r}_{i}, \mathbf{r}_{j}\right)$ are the Coulomb interaction terms and $E_{\text {gap }}$ the bulk band gap.

Dielectric confinement is important in colloidal NPLs, owing to the strong mismatch between the inorganic NPL and the organic surroundings. Because the organic environment screens electric fields more weakly than the semiconductor lattice, it gives rise to enhanced Coulomb interactions. $\underline{\underline{9}} \mathbf{1 0 , 1 3}$ We model this effect using image-charge (IC) expressions developed for finite-width quantum wells. Self-energy corrections $(\Sigma)$ are included within the same formalism to account for the changes that individual carriers produce on their own dielectric environment. 47 In some instances, for the sake of comparison, the Coulomb enhancement arising from dielectric confinement is modeled using a RK potential instead, which is an approximation of the Coulomb potential for the limit case of a quantum well with zero thickness and static dielectric screening. . $^{48}$

To solve Hamiltonian (1), a variational trial wave function is defined for excitons:

$$
\begin{equation*}
\Psi_{X}\left(\mathbf{r}_{\mathbf{e}}, \mathbf{r}_{\mathbf{h}}, \sigma_{e}, \sigma_{h}\right)=N_{X} \Phi_{e}\left(\mathbf{r}_{\mathbf{e}}\right) \Phi_{h}\left(\mathbf{r}_{\mathbf{h}}\right) J\left(r_{e h}\right) \tag{3}
\end{equation*}
$$

where $N_{X}$ is the normalization constant, $\Phi_{e}$ and $\Phi_{h}$ are the envelope functions of noninteracting electron and hole, and $J\left(r_{e h}\right)=e^{-r_{e h} / r_{B}^{X}}$ is a Slater correlation factor, with $r_{e h}$ the electron-hole separation and $r_{B}^{X}$ the effective exciton Bohr radius, which is the variational parameter to optimize. For negative trions, the ground state involves double occupancy of the lowest electron orbital (associated to singlet spin) plus one hole. Then, a Slater-Jastrow trial wave function is used:

$$
\begin{equation*}
\Psi_{X^{-}}\left(\mathbf{r}_{\mathbf{e}_{\mathbf{1}}}, \mathbf{r}_{\mathbf{e}_{2}}, \mathbf{r}_{\mathbf{h}_{\mathbf{1}}}, \sigma_{e_{1}}, \sigma_{e_{2}}, \sigma_{h_{1}}\right)=N_{X^{-}} \Phi_{e}\left(\mathbf{r}_{\mathbf{e}_{\mathbf{1}}}\right) \Phi_{e}\left(\mathbf{r}_{\mathbf{e}_{\mathbf{2}}}\right) \Phi_{h}\left(\mathbf{r}_{\mathbf{h}_{1}}\right) J\left(r_{1}, r_{2}, r_{12}\right) \tag{4}
\end{equation*}
$$

Here, $N_{X^{-}}$the normalization factor and $J\left(r_{1}, r_{2}, r_{12}\right)=e^{-r_{1} / r_{B}^{X^{-}}} e^{-r_{2} / r_{B}^{X^{-}}} e^{\frac{b r_{12}}{1+a r_{12}}}$ the Jastrow factor, with $r_{1}=\left|\mathbf{r}_{\mathrm{e}_{1}}-\mathbf{r}_{\mathrm{h}_{1}}\right|, r_{2}=\left|\mathbf{r}_{\mathrm{e}_{2}}-\mathbf{r}_{\mathrm{h}_{1}}\right|$ and $r_{12}=\left|\mathbf{r}_{\mathrm{e}_{1}}-\mathbf{r}_{\mathrm{e}_{2}}\right|$. In this case, $r_{B}^{X^{-}}, b$ and $a$ are the variational parameters to optimize. The first one is related to attractions and the others to repulsions. Analogous expressions are used for positive trions.

Variational optimization is carried out using a VQMC algorithm, with the freely available codes we developed in Ref. 39. Iterative Newton-Rhapson convergence is compared with sequential optimization of the variational parameters to avoid local minima. The optical recombination probability for the resulting wave functions can be estimated within the dipole approximation. $\underline{49}$ For a neutral exciton, the transition from $\left|\Psi_{X}\right\rangle$ to a vacuum state $|0\rangle$ is proportional to the electron-hole overlap: $\underline{ }^{\underline{13}}$

$$
\begin{equation*}
\left.\tau_{X \rightarrow 0}^{-1} \propto 1 / 2\left|\langle 0| \delta_{\mathbf{r}_{e}, \mathbf{r}_{\mathbf{h}}}\right| \Psi_{X}\right\rangle\left.\right|^{2}=\frac{1}{2}\left(\frac{N_{X}}{N_{e} N_{h}}\right)^{2} . \tag{5}
\end{equation*}
$$

where $N_{i}$ is the normalization constant of a single-particle orbital $\Phi_{i}, N_{e}=N_{h}=\sqrt{8 /\left(L_{x} L_{y} L_{z}\right)}$ in our particle-in-box functions, with $L_{x}, L_{y}$ and $L_{z}$ the NPL dimensions. The $1 / 2$ factor
accounts for spin selection rules forbidding optical transitions in dark excitons. For a negative trion, the transition from $\left|\Psi_{X}^{-}\right\rangle$to an electron state $\left|\Psi_{e}\right\rangle=N_{e} \Phi_{e}\left(\mathbf{r}_{\mathbf{e}_{1}}\right)$ is proportional to:

$$
\begin{equation*}
\left.\tau_{X^{-} \rightarrow e}^{-1} \propto\left|\left\langle\Psi_{e}\right| \delta_{\mathbf{r}_{\mathrm{e}_{2}}, \mathbf{r}_{\mathbf{h}_{1}}}\right| \Psi_{X^{-}}\right\rangle\left.\right|^{2}=\left(N_{e} N_{X^{-}} \mathcal{I}\right)^{2} \tag{6}
\end{equation*}
$$

with $\mathcal{I}=\int \Phi_{e}\left(\mathbf{r}_{\mathbf{e}_{1}}\right)^{2} \Phi_{e}\left(\mathbf{r}_{\mathbf{e}_{2}}\right) \Phi_{h}\left(\mathbf{r}_{\mathbf{e}_{2}}\right) e^{-r_{12} / r_{B}^{X^{-}}} e^{\frac{b r_{12}}{1+a r_{12}}} d^{3} r_{e_{1}} d^{3} r_{e_{2}}$.

## Results

We investigate excitons and trions in CdSe and PbS NPLs with cubic crystal lattice. Material parameters are summarized in Table 1. For CdSe, we consider NPLs with 4.5 monolayer thickness ( $L_{z}=1.4 \mathrm{~nm}$ ), as in the samples measured in Refs. 28 and 29. For PbS , we choose a typical thickness of $7-8$ monolayers $\left(L_{z}=2.0 \mathrm{~nm}\right)$. $\underline{50}$ Unless otherwise stated, for both CdSe and PbS NPLs we consider an environmental dielectric constant due to the organic ligands of $\varepsilon_{\text {out }}=2 . \underline{9.51}$

Table 1: Material parameters used in the calculations. $\varepsilon_{0}$ is the vacuum permittivity, $m_{0}$ is the free electron mass and $a_{0}$ stands for the lattice constant. The references indicate the data source.

| Parameter | CdSe | PbS | Units |
| :---: | :--- | :--- | :---: |
| $\varepsilon_{N P L}$ | $10^{\underline{52}}$ | $17^{53}$ | $\varepsilon_{0}$ |
| $m_{\perp, e}$ | $0.22^{\underline{10}}$ | $0.27^{\underline{21}}$ | $m_{0}$ |
| $m_{\perp, h}$ | $0.41 \underline{10}$ | $0.19^{\underline{21}}$ | $m_{0}$ |
| $m_{z, e}$ | $0.4^{\underline{13}}$ | $0.29^{\underline{21}}$ | $m_{0}$ |
| $m_{z, h}$ | $0.99^{\underline{13}}$ | $0.25^{\underline{21}}$ | $m_{0}$ |
| $E_{\text {gap }}$ | $1.76^{\underline{52}}$ | $0.41^{\underline{54}}$ | eV |
| $a_{0}$ | $6.08^{\underline{52}}$ | $5.935^{\underline{55}}$ | $\AA$ |

## Binding Energy

We start by studying the effect of lateral confinement on the binding energy of excitons and trions. For excitons, the binding energy is calculated as $E_{b}(X)=E_{e}+E_{h}-E(X)$, with $E(X)$ the the total exciton energy and $E_{e / h}$ that of an independent electron/hole. For the
trion, it is defined as $E_{b}\left(X^{ \pm}\right)=E(X)+E_{h / e}-E\left(X^{ \pm}\right)$, where $E\left(X^{ \pm}\right)$is the total energy of the (positive or negative) trion. We take a NPL with one fixed lateral side ( $L_{x}=20$ nm ) and vary the other side $\left(L_{y}\right)$. The results are represented as blue squares in Figure 1. In the case of excitons, we also plot the binding energies obtained with a semi-analytic variational method,,$\underline{13}$ blue circles in Fig. $\mathbb{1}(\mathrm{a})$ and (b). The excellent agreement between the two methods validates the performance of the VQMC approach, which has the advantage of being computationally efficient for trions as well.

Figs. [1(a) and (b) show that the exciton binding energies in NPLs are large, which is a result of the quasi-2D geometry and the strong dielectric confinement. For CdSe NPLs, the values (225-265 meV) are consistent with previous theoretical estimates, $\underline{\underline{9}, 10,13,29}$ and experimental measurements. $\underline{56}$ In PbS NPLs, the binding energies (115-145 meV) exceed those calculated by Yang and Wise for quantum wells $(\sim 80 \mathrm{meV})$. $\xlongequal{11}$ This is a consequence of the smaller thickness in our NPLs ( $L_{z}=2 \mathrm{~nm}$ vs. $L_{z}=3 \mathrm{~nm}$ in their work), and suggests that recent progress in the synthesis of thin PbS NPLs 50.57 .58 should facilitate the observation of robust excitonic effects. Also, our results evidence that PbS NPLs can benefit from a significant modulation of the binding energy with lateral confinement, starting at large lateral dimensions well above the PbS excitonic Bohr radius ( $L_{y}<30 \mathrm{~nm}$ ).

Figs.1(c) and (d) show the calculated trion binding energies for negative (blue squares) and positive (red squares) trions. The modulation of $E_{b}\left(X^{ \pm}\right)$by lateral confinement is evident. In the case of CdSe , it enables binding energies greater than thermal energy at room temperature ( 24 meV ) when $L_{y}<15 \mathrm{~nm}$, which is consistent with Ref. 29 experiments. Even in the case of PbS , which has a large dielectric constant, the trion binding energies are one order of magnitude greater than those of epitaxial quantum wells. $\underline{59}$ For both materials and all dimensions under study, trions are bound $\left(E_{b}\left(X^{ \pm}\right)>0\right)$, which should be seen in experiments as a redshifted emission when compared to excitons. This is a consequence of the strong Coulomb correlation, and is in contrast to small CdSe nanocrystals. $\underline{\underline{28}, \underline{60} \text {. }}$

Previous theoretical simulations of trions in NPLs using effective mass formalism으의 intro-


Figure 1: Binding energies as a function of lateral NPL confinement for: (a) CdSe exciton, (b) PbS exciton, (c) CdSe trions and (d) PbS trions. Squares are used for calculations using VQMC and circles for those using a semi-analytic variational calculation. IC and RK potentials describing dielectric confinement are also compared. Lines are guides to the eye. Fluctuations around them are due to the statistical nature of VQMC calculations. Insets: schematics of the NPLs under study.
duced dielectric effects in Coulomb interactions through a RK potential. ${ }^{61}$ Although computationally this is a very efficient approximation, the potential was originally devised for
 performance in colloidal NPLs, whose thickness can reach few nm, has not been tested. In

Fig. [1 we compare the binding energies calculated with RK and IC potentials. For excitons, RK simultations (green squares in Fig. [1(a,b)) underestimate the binding energy by 5 -10\% (cf. blue squares). For trions, however, RK and IC energies match within 1 meV difference. Since effective mass models are meant to provide qualitative and semi-quantitative estimates, these results support the use of the RK approximation to calculate binding energies in colloidal NPLs with typical (few monolayer) thicknesses. Nonetheless, for estimates of the emission energies, the RK potential must be complemented with self-energy corrections, as we show in the next section.

## Modulation of dielectric confinement




Figure 2: Shift of emission energy (solid line), net Coulomb energy (dashed line) and selfenergy (dotted line) as a function of the dielectric constant in the environment in (a) CdSe NPL and (b) PbS NPL. All energies are referred to the $\varepsilon_{o u t}=\varepsilon_{N P L}$ case. Different symbols are used for excitons and trions. The NPL has $20 \times 10 \mathrm{~nm}^{2}$ area. The insets zoom in on the emission blueshift for excitons and trions, which results from $\Sigma$ exceeding the net Coulomb energy.

The dielectric confinement exerted by the organic environment has been known to influence the electronic properties of excitons in colloidal NPLs since early studies. $\underline{\underline{9}}$ The low dielectric constant of the organic medium enables strong Coulomb interactions, which give rise to large $E_{b}(X)$ values. The influence on negative trions was recently calculated in

Ref. 29. It was concluded that with increasing dielectric mismatch between the NPL and the surroundings, $E_{b}\left(X^{-}\right)$increases and its emission energy decreases, all because of the weaker screening of electron-hole attraction. The simulations however missed the self-energy correction $\Sigma$, which accounts for the effect of the polarization induced by the carriers on themselves.

In Fig. 2 we extend the study of dielectric confinement by comparing neutral excitons with both negative and positive trions in CdSe and PbS NPLs, as a function of the dielectric constant in the environment, $\varepsilon_{\text {out }}$. For all magnitudes under study, the reference energy is set to the case without dielectric mismatch, $\varepsilon_{o u t}=\varepsilon_{N P L}$. As can be seen, in spite of the Coulomb repulsions the behavior of $\mathrm{X}^{-}$(triangles) and $\mathrm{X}^{+}$(squares) is similar to that of neutral excitons (dots). Namely, the net Coulomb interaction -i.e. the expectation value of attractions plus repulsions, not to be confused with the binding energy - (dashed line) becomes more and more attractive when $\varepsilon_{\text {out }}$ decreases. The enhancement of the attractions is however compensated by an increase of the self-energy correction, $\Sigma$ (dotted line). The latter term is greater than the former, which translates into an overall increase of the emission energy (solid line). Similar findings have been observed for excitons in $\mathrm{PbS} \underline{\underline{11}}$ and $\mathrm{CdSe} \underline{\underline{13}}$ NPLs. The extension to trions implies that the emission wavelength in such species can be also blueshifted by increasing the dielectric confinement. To better see the magnitude of this effect, insets are included in Fig. 2, which show that the blueshift can be few tens of meV large. Energy shifts due to dielectric confinement have been proposed to be the driving mechanism for the formation of minibands in superlattices made of stacked NPLs. ${ }^{62}$ The results in Fig. 22 indicate that such bands could be built not only from excitons but from trions as well.

## Balance between attractions and repulsions

To visualize the relative strength of attractions and repulsions of trions in NPLs, we decompose the energy of excitons and trions as:

$$
\begin{align*}
E(X) & =E_{e}+E_{h}+V_{e h}(X)+E_{g a p}  \tag{7}\\
E\left(X^{-}\right) & =2 E_{e}+E_{h}+2 V_{e h}\left(X^{-}\right)+V_{e e}+E_{g a p}  \tag{8}\\
E\left(X^{+}\right) & =E_{e}+2 E_{h}+2 V_{e h}\left(X^{+}\right)+V_{h h}+E_{g a p} \tag{9}
\end{align*}
$$

where $E_{e}\left(E_{h}\right)$ is the expectation value of the electron (hole) single-particle terms in Hamiltonian (11), $V_{e h}$ that of the electron-hole Coulomb term and $V_{e e}\left(V_{h h}\right)$ that of electron-electron (hole-hole) Coulomb term.


Figure 3: (a) Expectation value of the Coulomb terms of excitons and trions, and (b) charge densities along the $x$ axis of the NPL in a CdSe NPL with $L_{x}=20 \mathrm{~nm}$ and $L_{y}=5 \mathrm{~nm}$.

Figure 3(a) shows the calculated values of Coulomb energies CdSe NPLs with varying lateral size $L_{y}$. The electron-hole attraction of positive and negative trions is found to be similar, and clearly smaller than the attractions, $\left|V_{e h}\left(X^{ \pm}\right)\right|=240-280 \mathrm{meV}$, while $\left|V_{e h}(X)\right|=300-320 \mathrm{meV}$. The repulsions are also similar for $X^{-}$and $X^{+}$, but much smaller in energy (160 - 200 meV ). Altogether, these findings indicate that the strong electronic correlations in colloidal NPLs make it possible for the trion to minimize repulsions and
maximize attractions, as attractive and repulsive terms would be identical in a strongly confined dot. $\underline{\underline{63}}$ This explains the sizable binding energies of trions reported in Fig. 1 .

The role of electronic correlations in deforming the wave functions to stabilize excitonic states can be observed in Fig. 3(b). For a neutral exciton, electron and hole show identical charge densities despite the different masses. For trions, the repulsions between the carriers in excess (e.g. electrons in $\mathrm{X}^{-}$) lead to somewhat larger delocalization, which reduces the electron-hole overlap substantially (note the smaller height of the charge density in the central region). These changes are reflected in the variational parameteres related to effective Bohr radii: $r_{B}^{X}=2.23 \mathrm{~nm}$ for the exciton, $r_{B}^{X^{-}}=2.53 \mathrm{~nm}$ and $r_{B}^{X^{+}}=2.98 \mathrm{~nm}$ for the trions. The consequences on the optical properties properties are significant, as we show in the next section.

## Emission spectra of CdSe NPLs

Having studied the general behavior of trions in NPLs, we next focus on the specific samples investigated in Ref. 29 and analyze their emission spectra. In Fig. 4(a) we compare the calculated emission energies of excitons and trions with those measured in the experiments. Our simulations overestimate the experimental values by $\sim 10 \mathrm{meV}$, but the overall agreement is good and, importantly, it is achieved with no fitting parameter. The redshift of trions with respect to excitons $(20-30 \mathrm{meV})$ is close to that of the experiments $(20-35$ meV ), which shows we obtain consistent binding energies. The larger value as compared to $\mathrm{CdSe} / \mathrm{CdS} / \mathrm{ZnS}$ core/shell/shell NPLs $\left(E_{b}\left(X^{-}\right)=10.5 \mathrm{meV}\right)^{28}$ can be explained from: (i) the stronger dielectric confinement in core-only NPLs, which has significant influence on trion binding energies, as seen in the inset of Fig. 2(a), and (ii) the quasi-type-II band alignment of $\mathrm{CdSe} / \mathrm{CdS}$, which promotes electron delocalization and hence reduced Coulomb interaction with the hole.

Fig. [4(b) compares the recombination probability of excitons and trions. For the smallest NPLs (area $17 \times 6 \mathrm{~nm}^{2}$ ), the probability is similar in all species. This is in spite of


Figure 4: Analysis of emission properties for the CdSe NPLs of Ref. 29. (a) Comparison of theoretical and experimental emission energies. (b) Calculated recombination probability. (c) Calculated ratio between oscillator strengths of trions and excitons. We include positive trions for completeness.
trions having no spin-forbidden (dark) optical recombination channels. The reason is that the repulsions in trions reduce the electron-hole overlap, as seen in the charge densities of Fig. 3(b). Consequently, the ratio of trion-to-exciton oscillator strength is about 0.45 (see leftmost part of Fig. [4(c)). With increasing lateral dimensions of the NPL, the giant oscillator strength effect boosts the recombination probability of X , which scales roughly linearly with the area. $\underline{64,65}$ This is not observed in trions instead. For $\mathrm{X}^{ \pm}$, the increase is much weaker and saturates for large areas $\left(>400 \mathrm{~nm}^{2}\right)$. The resulting oscillator strength for large area NPLs is then smaller than that of excitons. For the larger NPLs under consideration the ratio is $\sim 0.2,\left(\right.$ area $41 \times 13 \mathrm{~nm}^{2}$, see rightmost part of Fig. $\left.4(\mathrm{c})\right)$.

The oscillator strength ratios we obtain are in between those reported for $\mathrm{CdSe} / \mathrm{CdS} / \mathrm{ZnS}$ NPLs, $\underline{28}$ which are close to unity, and those calculated for CdSe NPLs in earlier studies, which range between 0.12 and 0.04 . ${ }^{29}$ The smaller values as compared to $\mathrm{CdSe} / \mathrm{CdS} / \mathrm{ZnS}$ can be interpreted from the absence of shells, which translates into larger dielectric mismatch. $\underline{\underline{6}}$ This gives rise to stronger electronic correlations, which in turn permit shaping wave functions to minimize repulsions. As for the larger values compared to Ref. 29 calculations, since both theoretical models rely on effective mass Hamiltonians, describe dielectric confinement with methods of similar outcome (Fig. (1), and provide good estimates of the experimentally observed emission and binding energies, the differences must be ascribed to the inclusion of many-body interactions in the wave function. Since VQMC calculations treat attractions and repulsions on equal footing, the resulting charge distribution of trions is less likely to overestimate the Bohr radius as compared to CI calculations. In this sense, it is not surprising that we obtain somewhat larger oscillator strengths.

The saturation of the trion oscillator strength beyond $400 \mathrm{~nm}^{2}$ in Fig. 4(b) is also in contrast to the linear increase in the calculations of Ref. 29. We note that our result is consistent with the expected behavior as one approaches the quantum well limit. In the formation of a (say, negative) trion, the initial electron is originally delocalized over the NPL volume, but it ends up being localized in the volume of the photocreated trion. This
localization leads to a reduction factor $1 / A$ in the oscillator strength as compared to the exciton, with $A=L_{x} L_{y}$ the NPL area - see for instance Eq. (13.51) in Ref. 66-. Since for the exciton, $\left.\left|\langle 0| \delta_{\mathbf{r}_{\mathbf{e}}, \mathbf{r}_{\mathbf{h}}}\right| \Psi_{X}\right\rangle\left.\right|^{2} \propto A, \underline{64,65}$ for the trion $\left.\left|\left\langle\Psi_{e}\right| \delta_{\mathbf{r}_{\mathbf{e}}, \mathbf{r}_{\mathbf{h}_{1}}}\right| \Psi_{X^{-}}\right\rangle\left.\right|^{2} \propto A^{0}$. Thus, for large NPLs we observe the 2D asymptotic behavior not only in the trion emission energies but also in its oscillator strength.

## Conclusions

We have compared exciton and trion optoelectronic properties in NPLs of CdSe and PbS. The pronounced electronic correlations in colloidal NPLs allow trions to reduce Coulomb repulsions while keeping attractions strong. A few signatures of this are observed. First, both negative and positive trions are redshifted with respect to the exciton, with binding energies that exceed room temperature thermal energy in the case of CdSe with narrow lateral dimensions. Second, contrary to excitons, the trion oscillator strength does not increase linearly with the NPL area, as the giant oscillator strength effect is significantly suppressed and vanishes for large areas.

Our calculations show that the description of dielectric confinement with simple 2D Rytova-Keldysh potentials provide similar estimates of binding energies to those of (fully 3D) image charge potentials in colloidal NPLs with typical (few-nm) thicknesses. However, they also evidence the need to add self-energy corrections so as to predict the right dependence of emission energy on the dielectric mismatch. These results are of interest for the design of optoelectronic devices using homostructured NPLs populated with trions.

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## Graphical TOC Entry



